

# isc N-Channel MOSFET Transistor

# 2SK3650-01L

### **FEATURES**

- Drain Current : I<sub>D</sub>= 33A@ T<sub>C</sub>=25 ℃
- Drain Source Voltage
  - : V<sub>DSS</sub>= 150V(Min)
- Static Drain-Source On-Resistance
  - :  $R_{DS(on)} = 70 \text{m} \Omega \text{ (Max)} @ V_{GS} = 10 \text{V}$
- 100% avalanche tested
- Minimum Lot-to-Lot variations for robust device performance and reliable operation



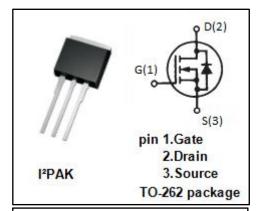
 motor drive, DC-DC converter, power switch and solenoid drive.

### ABSOLUTE MAXIMUM RATINGS(Ta=25°C)

SYMBOL	PARAMETER	VALUE	UNIT
V <sub>DSS</sub>	Drain-Source Voltage	150	V
V <sub>GS</sub>	Gate-Source Voltage-Continuous	±30	V
I <sub>D</sub>	Drain Current-Continuous	33	А
І <sub>ОМ</sub>	Drain Current-Single Pluse	132	А
P <sub>D</sub>	Total Dissipation @T <sub>C</sub> =25℃	150	W
TJ	Max. Operating Junction Temperature -55~150		$^{\circ}$
T <sub>stg</sub>	Storage Temperature -55~150		$\mathbb{C}$

#### THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	MAX	UNIT	
R <sub>th j-c</sub>	Thermal Resistance, Junction to Case	0.833	°C/W	



	E .	TZ TZ	A	F	7.
-0-	13	10		EM	D2
<u>G</u> <u>b2</u>		1 1	A2.		
		4			
· V	<u>.</u> V		_	y y	*

	MM		
DIM	MIN	MAX	
Α	4. 37	4.77	
A1	1. 22	1.42	
A2	2. 47	2.87	
b	0.7	0.97	
b2	1.17	1.42	
С	0.28	0.53	
D	23. 2	24. 02	
D1	8. 38	8.9	
D2	6	1	
E	9.9	10.39	
E4	7.3	1	
E	2. 54BSC		
G	1. 25	1.5	
H2	/	1. 31	
L	13.34	14.1	
L1	3. 3	4.06	
L3	0.95	1.15	

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#### **ELECTRICAL CHARACTERISTICS**

T<sub>c</sub>=25℃ unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	MAX	UNIT
V <sub>(BR)DSS</sub>	Drain-Source Breakdown Voltage	V <sub>GS</sub> = 0; I <sub>D</sub> = 0.25mA	150		V
V <sub>GS(th)</sub>	Gate Threshold Voltage	V <sub>DS</sub> = 10V; I <sub>D</sub> = 0.25mA	3.0	5.0	V
R <sub>DS(on)</sub>	Drain-Source On-Resistance	V <sub>GS</sub> = 10V; I <sub>D</sub> = 11.5A		70	m Ω
I <sub>GSS</sub>	Gate-Body Leakage Current	V <sub>GS</sub> = ±30V;V <sub>DS</sub> = 0		±0.1	uA
I <sub>DSS</sub>	Zero Gate Voltage Drain Current	V <sub>DS</sub> = 150V; V <sub>GS</sub> = 0		25	uA
V <sub>SD</sub>	Forward On-Voltage	I <sub>S</sub> = 23A; V <sub>GS</sub> = 0		1.65	V

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